

Low Current Superhet Remote Control Receiver

Description

The U4311B is a monolithic Integrated Circuit in bipolar technology for low-current UHF remote control super-heterodyne receivers in amplitude- or frequency-modulated mode. Typical applications are keyless car

lock-, alarm or telecontrol remote indication systems. Especially for automotive applications it supports a superhet design with about 1 mA total current consumption, as required by the car manufacturers.

Features

- Usable for amplitude- and frequency- modulated transmission systems
- Extremely low quiescent current approximately 1 mA in the stand-by mode due to wake-up concept
- Wide power supply voltage range 3 to 13 V
- Sensitive IF-amplifier for 10.7 MHz operating frequency
- Logarithmic AM demodulator

- FM demodulator
- Monoflop output to wake up a microcontroller
- High performance operational amplifier to realize a data recovering filter
- Non-inverting clamping comparator with amplitudedepending hysteresis for data regeneration
- Small SSO20 package

Block Diagram

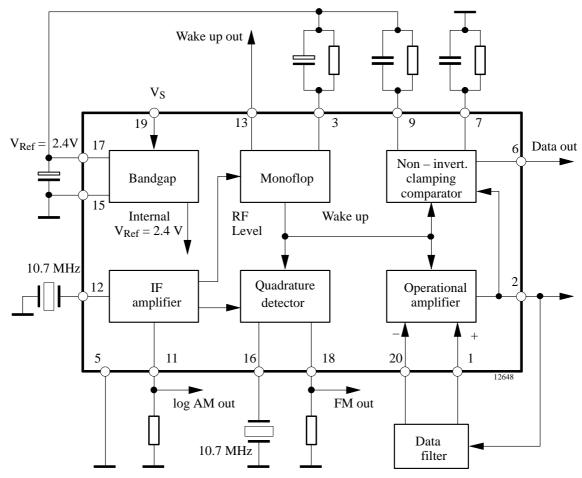


Figure 1. Block diagram

U4311B-FS



Pin Description

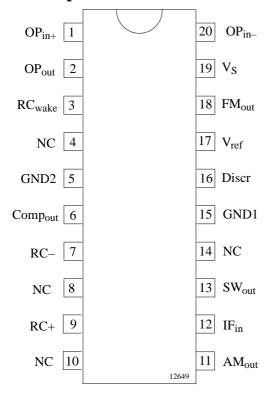


Figure 2. Pinning

Pin	Symbol	Function	
1	OP _{in+}	OP amplifier non inverted input	
2	OP _{out}	OP amplifier output	
3	RCwake	RC wake up reset time	
4	NC	Not connected	
5	GND2	Ground of the logical circuits	
6	Comp _{out}	Comparator output	
7	RC-	Comparator time constant	
8	NC	Not connected	
9	RC+	Comparator time constant	
10	NC	Not connected	
11	AM _{out}	AM current output	
12	IF _{in}	IF input	
13	SW _{out}	Wake up output	
14	NC	Not connected	
15	GND1	Ground of the analog circuits	
16	Discr	FM discriminator tank	
17	V _{ref}	Reference voltage	
18	FM _{out}	FM discriminator output	
19	V _S	Supply voltage	
20	OP _{in} –	OP amplifier inverted input	

Internal connections see figures 4 to 19

Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Supply voltage	V_{S}	13	V
Power dissipation $T_{amb} = 85^{\circ}C$	P_{tot}	400	mW
Junction temperature	T_{i}	125	°C
Storage temperature	T_{stg}	-55 to +125	°C
Ambient temperature for SSO20	T_{amb}	-40 to +105	°C

Thermal Resistance

Parameters		Symbol	Value	Unit
Junction ambient	SSO20	R_{thJA}	140	K/W



Electrical Characteristics

 $V_S = 5 \ \text{V}, \ T_{amb} = 25 \text{°C}, \ f_{in} = 10.7 \ \text{MHz}; \ \text{FM part:} \ f_{mod} = 1 \ \text{kHz}, \ f_{dev} = 22.5 \ \text{kHz}; \ \text{AM part:} \ f_{mod} = 1 \ \text{kHz}, \ m = 100\% \ \text{unless otherwise specified}$

Parameters	Test Co	nditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Characteristics					•		
Supply voltage range		Pin 19	V _S	3		12	V
Quiescent supply current		Pin 19	I_q		1	1.3	mA
Active supply current		Pin 19	I _{act}		2.8	3.6	mA
Bandgap	•					•	
Regulated voltage		Pin 17	V _{ref}	2.3	2.4	2.5	V
Output current		Pin 17	I_{ref}			5	mA
Source resistance		Pin 17	R _{ref}		2.3	5	Ω
External capacitor		Pin 17	C _{ref}	10			μF
Power supply rejection	f = 50 Hz	Pin 17	psrr		60		dB
ratio			-				
IF amplifier							
Input resistance		Pin 12	R _{in}	180	330	520	Ω
Input capacitance		Pin 12	C _{in}		5		pF
Typical internal 3 dB	IF level 70		f _{3dB}	8		12	MHz
frequency		Pins 12 and 18					
−3 dB limiting point		Pin 12	V _{FM3dB}		30		dΒμV
Recovered data voltage		Pin 18	V _{FMout}	50	130	230	mV
FM detector output resis-		Pin 18	R _{FMout}		50		kΩ
tance							
AM rejection ratio	m = 30%	Pins 12 and 18	AM_{rr}		25		dB
Maximum AM input		Pin 12	V _{AMmax}		90		dΒμV
voltage							
AM quiescent current		Pin 11	I _{AMout}	10	22	37	μΑ
Maximum AM current		Pin 11	I _{AMoutmax}		100		μΑ
Operational amplifier			1		1		1
Gain bandwidth product		Pins 1, 2 and 20	f _t	3	4	6.5	MHz
Excess phase		Pins 1, 2 and 20	δ		80		degree
Open loop gain		Pins 1, 2 and 20	g 0	50	70	95	dB
Output voltage range		Pin 2	ΔV_{out}		1.55		V
Common mode input voltage		Pins 1 and 20	V _{in}	0.7		1.7	V
Input offset voltage		Pins 1 and 20	V _{os}	-2.5	0	+2.5	mV
Maximum output current		Pin 2	I _{out}			5	mA
Common mode rejection		Pin 1 and 20	cmrr	65	85		dB
ratio							
Total harmonic distortion		mV, f = 33 kHz, circuit Pin 2	thd		1	3	%
Power supply rejection ratio	f = 50 Hz	Pin 2	psrr	65	85		dB

U4311B-FS



Parameters	Parameters Test Conditions / Pins		Min.	Тур.	Max.	Unit
Clamping comparator						
Typical common mode Pin 2		V _{cmvr}	0.8		1.6	V
input voltage range						
Maximum distortion	$V_{\text{signal}} = 100 \text{ mV},$	V _{dmax}			200	mV
voltage	$R + = R - = 50 \text{ k}\Omega,$					
	C+ = C- = 200 nF,					
	$f_{\text{disto}} = 50 \text{ Hz},$					
	$f_{signal} = 1 \text{ kHz}$ Pin 2					
Output voltage	$V_2 > (V_7 + V_9)/2$	V _{cout}		V_{Ref}		1)
	$(10 \text{ k}\Omega \text{ load to } V_{Ref})$					
	Pin 6					
Output voltage	$V_2 < (V_7 + V_9)/2$	V_{cout}	0	150	250	mV
	$(10 \text{ k}\Omega \text{ load to } V_{\text{Ref}})$					
	Pin 6					
Wake up circuit		Γ	1	1		
Minimum wake up level	Pin 12	V _{in}		40		$dB\mu V^{2)}$
Internal charging resistor	Pin 3	R _{int}		1.5		kΩ
Threshold voltage	Pin 3	V_{th}		1.6		V
Output switch current	Pin 13	I_{SW}	180	250	550	μΑ
Output switch voltage Pin 13		V_{SW}			5.5	V 3)
External wake up resistor	Pins 3 and 17	R _{WU}	22			kΩ
External wake up capacitor Pins 3 and 17		C_{WU}			10	μF
Hold time (± 30%)		t _h	\approx 1.5 \times R _{WU} \times C _{WU}			s 4)
Delay time (± 30%)		t _d	≈ 0	$C_{\rm WU} \times 0.75$	5 kΩ	s ⁴⁾

- 1) IC version with inverting comparator available: U4313B
- 2) Measured at Pin 9, (12) referred to 330 Ω
- 3) Protected by a Z-diode, see figure 13
- 4) Valid for 0.1 μ F \leq C_{WU} \leq 10 μ F and 22 $k\Omega \leq$ R_{WU} \leq 680 $k\Omega$

Application

The U4311B-FS is well-suited to implement UHF remote control or data transmission systems, based on a low-current superheterodyne receiver concept. SAW-devices may be used in the transmitter as well as in the receiver local oscillator. The front end should be a discrete circuit application with low current UHF-transistors like S822T or S852T from TEMIC TELEFUNKEN microelectronic GmbH. The frequency of the local oscillator can be determined either by coaxial resonators or SAW-devices. Due to large SAW-resonator tolerance an IF-bandwidth — and

in a FM-system additionally the discriminator amplitude characteristic (see figure 28) — of 300 kHz or higher is proposed. As the circuit needs only 3.0 V supply voltage for operation the front end may be a stacked design in order to achieve a total receiver current consumption of approximately 1 mA. Figure 29 shows a principle receiver concept diagram. The application notes ANT012, ANT013, and ANT015 contain more detailed information on complete RF links.



Circuit Description

General Functions

The integrated circuit U4311B includes the following functions: IF-amplifier, FM-demodulator, wake-up circuit with monoflop, operational-amplifier, non-inverting data comparator and voltage-regulator.

The 10.7 MHz IF-signal from the front end passes the integrated IF-amplifier which operates for amplitude- or frequency-modulated signals to either a logarithmic AM-demodulator which was implemented to avoid settling time problems effected by use of an automatic gain control system or a quadrature detector for FM. A data shaping filter — advantageously realized with the internal high performance operational-amplifier — reduces system bandwidth to an optimized compromise regarding transmission distance and data recognition. Thus, an optimal bit error rate can be achieved without any further active component.

The comparator connected to the output of the filter has a level-dependent hysteresis and clamps its reference voltage to the signal minimum and maximum peaks as described later.

Without IF-input signal — in the normal mode — only the IF-amplifier and the AM demodulator which operates as

a level strength indicator are activated. If the level of the IF signal increases, the whole circuitry is turned on by the wake-up circuit. This signal is externally available at Pin 13 and can be used to wake up a microcontroller. After an adjustable reset time, determined by the monoflop time constant, the integrated circuit rests down to the sleep mode. In this case typically 1 mA supply current is required. An external resistor matched at pin 3 to ground blocks the wake-up circuit and gives fully function at lower IF-level as to recognize in figures 24 and 27, but supply current increases up to typically 2.8 mA.

Function of the Clamping Comparator

The output signal of the operational amplifier is fed to the input of the non-inverting comparator and two peak detectors (Q1 and Q2, figure 3). Their time constants are distinguished by RC+ and RC-. The components value must be adapted to the transmission code. The time constant should be large compared to the bit-rate for optimized noise and hum suppression. To compensate the input transistors base-emitter-voltage differences these two signals are buffered by Q3 and Q4. The mean value is used as comparator threshold, the difference of the peak values controls the hysteresis. This clamping comparator works as a data regenerator.

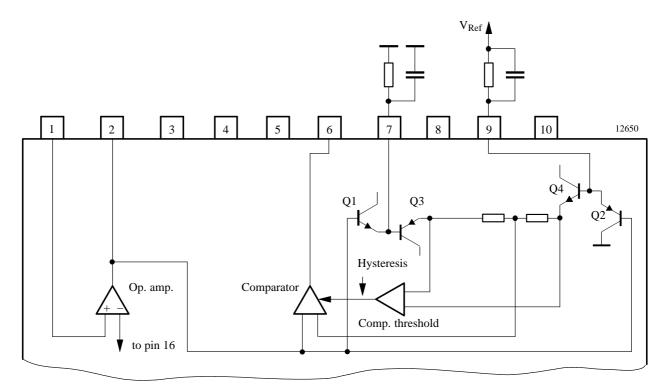


Figure 3. Principle function of the clamping comparator



Internal Pin Circuitry

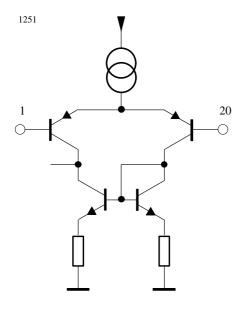


Figure 4. Pin 1 OP_{in+}

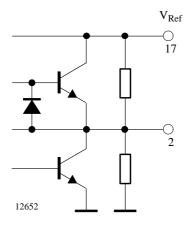


Figure 5. Pin 2 OP_{out}

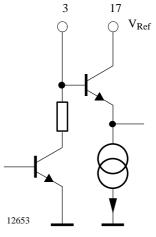


Figure 6. Pin 3 RC_{wake}



Figure 7. Pin 5 GND2

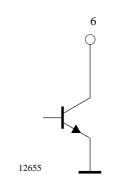


Figure 8. Pin 6 Compout

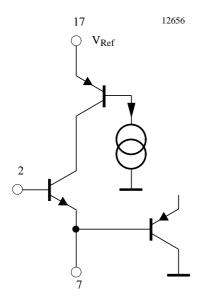


Figure 9. Pin 7 RC-

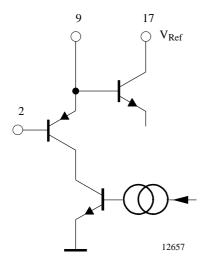


Figure 10. Pin 9 RC+

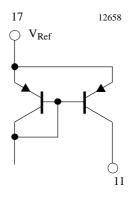


Figure 11. Pin 11 AM_{out}

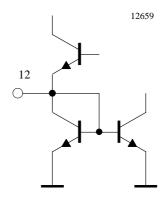


Figure 12. Pin 12 IF_{in}

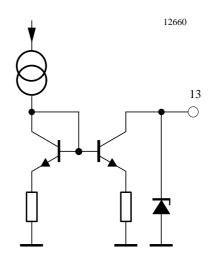


Figure 13. Pin 13 SW_{out}



Figure 14. Pin 15 GND1

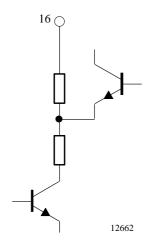


Figure 15. Pin 16 Discr

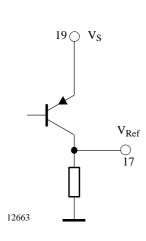


Figure 16. Pin 17 V_{Ref}

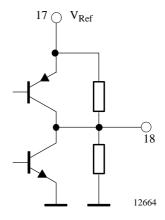


Figure 17. Pin 18 FM_{out}



Figure 18. Pin 19 V_S

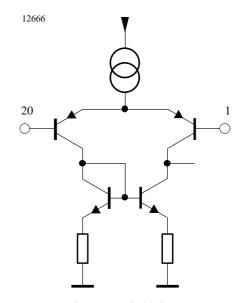


Figure 19. Pin 20 OP_{in-}

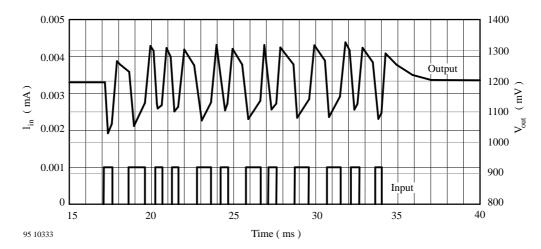


Figure 20. Time domain response of 2 kHz Bessel low pass data filter

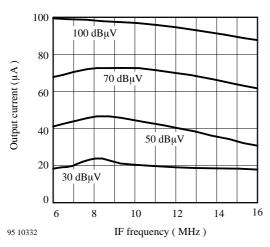


Figure 21. IF-frequency response

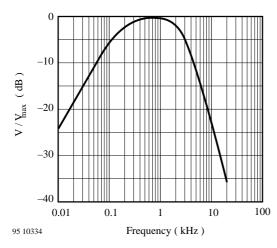


Figure 22. Frequency response of 2 kHz Bessel low pass data filter

Data Recovering Filter

The test circuit in figures 23 and 26 includes an example of a data recovering filter realized with the components R_1, R_2, C_1, C_2, C_3 . It is of a second order Bessel type with low pass characteristic, a 3 dB cut-off frequency of 2 kHz and an additional high pass characteristic for suppressing dc and low frequency ac components. Simulation of time domain and frequency response is drawn in figures 20 and 22. This filter gives a typical application of a 1 kBaud Manchester code amplitude modulated transmission.

The capacitor C_2 is responsible for the high pass cut-off frequency. For a correct pulse response this high pass cut-off frequency should be as low as possible. Figure 20 shows the transient response and the influence of the dc component. The first pulses might be wrong if the high pass cut-off frequency is too low. For this reason some burst bits must be transmitted before the real data transmission starts. On the other hand, if the cut-off frequency is too high, you might get in trouble with roof shaping of the rectangle pulses at the operational amplifier output.

The low pass cut-off frequency and the maximum transimpedance V_{out}/I_{in} are distinguished by the further external elements. Careful design of the data filter gives optimized transmission range. For designing other filter parameters look for filter design handbooks or programs or request TEMIC TELEFUNKEN microelectronic GmbH for support. Some proposals can be found in the application notes ANT012, ANT013 and ANT015.



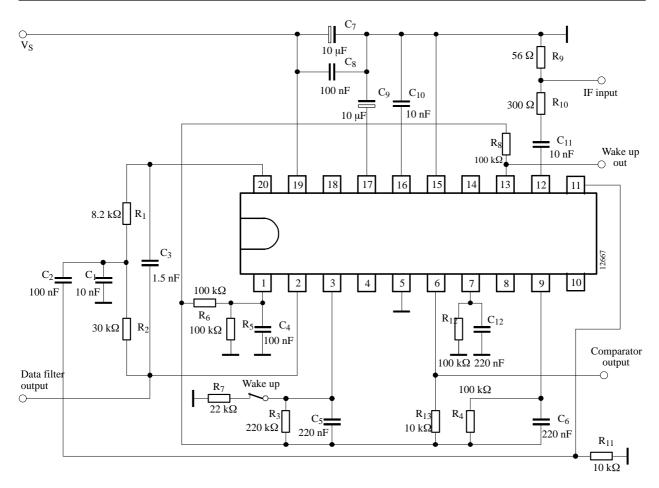


Figure 23. AM test circuit with 2 kHz Bessel low pass data filter

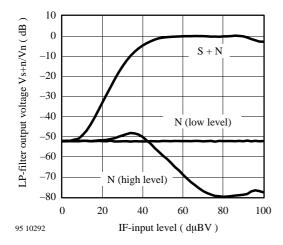


Figure 24. Signal to noise ratio AM

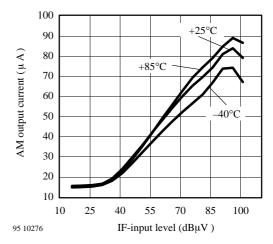


Figure 25. AM-demodulator characteristic vs. temperature

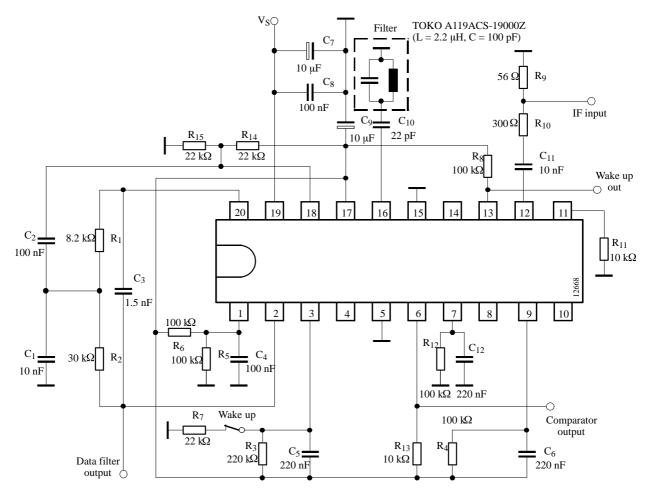


Figure 26. FM test circuit with 2 kHz Bessel low pass data filter

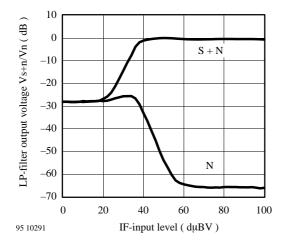


Figure 27. Signal to noise ratio FM; deviation 22.5 kHz

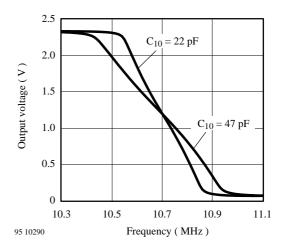


Figure 28. FM-discriminator characteristic



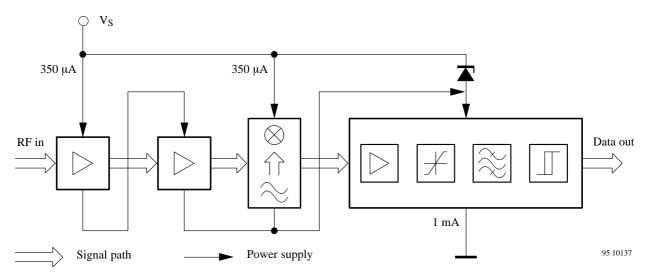


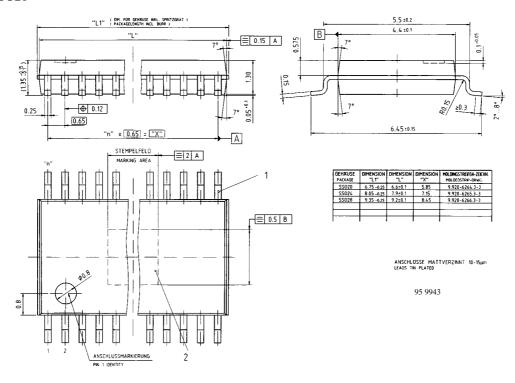
Figure 29. Principle diagram UHF remote control receiver

Ordering Information

Extended Type Number	Package	Remarks
U4311B-C	DIP16	
U4311B-CFL	SO16L	
U4311B-CFS	SSO20	Ambient temperature up to +105°C

Dimensions in mm

Package: SSO20





Ozone Depleting Substances Policy Statement

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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